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February 2016

# FODM3011, FODM3012, FODM3023, FODM3052, FODM3053 4-Pin Full Pitch Mini-Flat Package Random-Phase Triac Driver Output Optocouplers

## **Features**

- Compact 4-pin Surface Mount Package (2.4 mm Maximum Standoff Height)
- · Peak Blocking Voltage
  - 250V (FODM301X)
  - 400V (FODM302X)
  - 600V (FODM305X)
- · Safety and Regulatory Approvals:
  - UL1577, 3,750 VAC<sub>RMS</sub> for 1 Minute
  - DIN-EN/IEC60747-5-5, 565 V Peak Working Insulation Voltage

# **Applications**

- · Industrial Controls
- · Traffic Lights
- · Vending Machines
- Solid State Relay
- Lamp Ballasts
- · Solenoid/Valve Controls
- Static AC Power Switch
- Incandescent Lamp Dimmers
- Motor Control

# Description

The FODM301X, FODM302X, and FODM305X series consists of a GaAs infrared emitting diode driving a silicon bilateral switch housed in a compact 4-pin miniflat package. The lead pitch is 2.54 mm. They are designed for interfacing between electronic controls and power triacs to control resistive and inductive loads for 115 V/240 V operations.

# **Functional Schematic**

# ANODE 1 CATHODE 2 AMAIN 4 TERMINAL MAIN TERMINAL

Figure 1. Functional Schematic

# **Package Outlines**

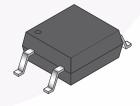


Figure 2. Package Outlines

# **Safety and Insulation Ratings**

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

| Parameter                                  | Characteristics        |           |
|--|------------------------|-----------|
| Installation Classifications per DIN VDE   | < 150 V <sub>RMS</sub> | I–IV      |
| 0110/1.89 Table 1, For Rated Mains Voltage | < 300 V <sub>RMS</sub> | I–III     |
| Climatic Classification                    |                        | 40/100/21 |
| Pollution Degree (DIN VDE 0110/1.89)       |                        | 2         |
| Comparative Tracking Index                 |                        | 175       |

| Symbol                | Parameter  | Value             | Unit              |
|-----------------------|--|-------------------|-------------------|
| V                     | Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$ , Type and Sample Test with $t_m = 10 \text{ s}$ , Partial Discharge < 5 pC             | 904               | V <sub>peak</sub> |
| V <sub>PR</sub>       | Input-to-Output Test Voltage, Method B, V <sub>IORM</sub> x 1.875 = V <sub>PR</sub> , 100% Production Test with t <sub>m</sub> = 1 s, Partial Discharge < 5 pC | 1060              | V <sub>peak</sub> |
| V <sub>IORM</sub>     | Maximum Working Insulation Voltage   | 565               | $V_{peak}$        |
| $V_{IOTM}$            | Highest Allowable Over-Voltage   | 6000              | $V_{peak}$        |
|                       | External Creepage  | ≥ 5               | mm                |
|                       | External Clearance   | ≥ 5               | mm                |
| DTI                   | Distance Through Insulation (Insulation Thickness)   | ≥ 0.4             | mm                |
| T <sub>S</sub>        | Case Temperature <sup>(1)</sup>  | 150               | °C                |
| I <sub>S,INPUT</sub>  | Input Current <sup>(1)</sup>   | 200               | mA                |
| P <sub>S,OUTPUT</sub> | Output Power <sup>(1)</sup>  | 300               | mW                |
| R <sub>IO</sub>       | Insulation Resistance at T <sub>S</sub> , V <sub>IO</sub> = 500 V <sup>(1)</sup>   | > 10 <sup>9</sup> | Ω                 |

## Note:

1. Safety limit values – maximum values allowed in the event of a failure.

# **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.  $T_A = 25^{\circ}C$  unless otherwise specified.

| Symbol               | Parameter                                   | Parameter                                   |                | Unit        |  |
|----------------------|---|---|----------------|-------------|--|
| T <sub>STG</sub>     | Storage Temperature                         |   | -55 to +150    | °C          |  |
| T <sub>OPR</sub>     | Operating Temperature                       |   | -40 to +100    | °C          |  |
| T <sub>J</sub>       | Junction Temperature                        |   | -40 to +125    | °C          |  |
| T <sub>SOL</sub>     | Lead Solder Temperature                     |   | 260 for 10 sec | °C          |  |
| EMITTER              |   |   |                |             |  |
| I <sub>F</sub> (avg) | Continuous Forward Current                  |   | 60             | mA          |  |
| I <sub>F</sub> (pk)  | Peak Forward Current (1 µs pulse, 300 pps.) | Peak Forward Current (1 µs pulse, 300 pps.) |                |             |  |
| V <sub>R</sub>       | Reverse Input Voltage                       |   | 3              | V           |  |
| P <sub>D</sub>       | Power Dissipation (No derating required ove | r operating temp. range)                    | 100            | mW          |  |
| DETECTOR             |   |   |                |             |  |
| I <sub>T(RMS)</sub>  | On-State RMS Current                        |   | 70             | mA<br>(RMS) |  |
|                      | /   | FODM3011, FODM3012                          | 250            |             |  |
| $V_{DRM}$            | Off-State Output Terminal Voltage           | FODM3022, FODM3023                          | 400            | V           |  |
|                      | FODM3052, FODM305                           |   | 600            |             |  |
| P <sub>D</sub>       | Power Dissipation (No derating required ove | r operating temp. range)                    | 300            | mW          |  |

### **Electrical Characteristics**

 $T_A = 25$ °C unless otherwise specified.

# **Individual Component Characteristics**

| Symbol           | Parameter                                  | Test Conditions                               | Device  | Min.  | Тур. | Max. | Unit |
|------------------|--|---|---|-------|------|------|------|
| EMITTER          |  |   |   |       |      |      |      |
| V <sub>F</sub>   | Input Forward Voltage                      | I <sub>F</sub> = 10 mA                        | All   |       | 1.20 | 1.50 | V    |
| I <sub>R</sub>   | Reverse Leakage Current                    | $V_R = 3 \text{ V}, T_A = 25^{\circ}\text{C}$ | All   |       | 0.01 | 100  | μΑ   |
| DETECTO          | DETECTOR                                   |   |   |       |      |      |      |
| I <sub>DRM</sub> | Peak Blocking Current Either Direction     | Rated $V_{DRM}$ , $I_F = 0^{(2)}$             | All   |       | 2    | 100  | nA   |
| dV/dt            | Critical Rate of Rise of Off-State Voltage | I <sub>F</sub> = 0 (Figure 8) <sup>(3)</sup>  | FODM3011,<br>FODM3012,<br>FODM3022,<br>FODM3023 |       | 10   |      | V/µs |
|                  |  |   | FODM3052,<br>FODM3053                           | 1,000 |      |      |      |

### Notes:

- 2. Test voltage must be applied within dv/dt rating.
- 3. This is static dv/dt. See Figure 1 for test circuit Commutating dv/dt is function of the load-driving thyristor(s) only.

### **Transfer Characteristics**

| Symbol                              | Parameter                              | Test Conditions                    | Device                             | Min. | Тур. | Max. | Unit |
|-------------------------------------|--|------------------------------------|------------------------------------|------|------|------|------|
| I <sub>FT</sub> LED Trigger Current |  | FODM3011,<br>FODM3022,<br>FODM3052 |                                    |      | 10   | mA   |      |
| 11-1                                | I <sub>FT</sub> LED Irigger Current    | Voltage = 3 V <sup>(4)</sup>       | FODM3012,<br>FODM3023,<br>FODM3053 |      |      | 5    | IIIA |
| I <sub>H</sub>                      | Holding Current, Either Direction      |                                    | All                                |      | 300  |      | μΑ   |
| $V_{TM}$                            | Peak On-State Voltage Either Direction | I <sub>TM</sub> = 100 mA peak      | All                                |      | 1.7  | 3    | V    |

### Notes:

4. All devices are guaranteed to trigger at an I<sub>F</sub> value less than or equal to max I<sub>FT</sub>. Therefore, recommended operating I<sub>F</sub> lies between max I<sub>FT</sub> (10 mA for FODM3011, FODM3022, and FODM3052, 5 mA for FODM3012, FODM3023, and FODM3053) and absolute max I<sub>F</sub> (60 mA).

### **Isolation Characteristics**

| Symbol        | Parameter                         | Test Conditions                | Device | Min.  | Тур. | Max. | Unit               |
|---------------|-----------------------------------|--------------------------------|--------|-------|------|------|--------------------|
| $V_{\rm ISO}$ | Steady State Isolation<br>Voltage | 1 Minute,<br>R.H. = 40% to 60% | All    | 3,750 |      |      | VAC <sub>RMS</sub> |

# **Typical Performance Characteristics**

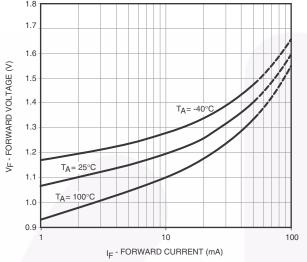


Fig. 3 LED Forward Voltage vs. Forward Current

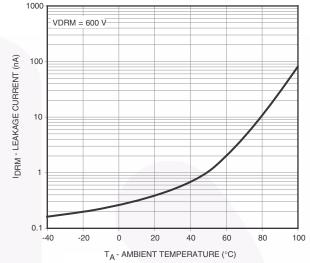


Fig. 4 Leakage Current vs. Ambient Temperature

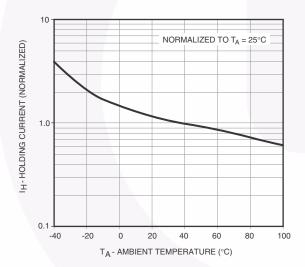


Fig. 5 Holding Current vs. Ambient Temperature

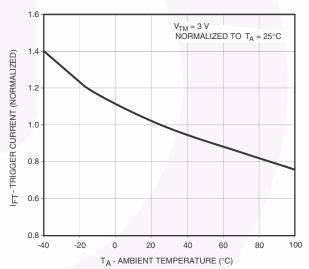


Fig. 6 Trigger Current vs. Ambient Temperature

# **Typical Performance Characteristics** (Continued)

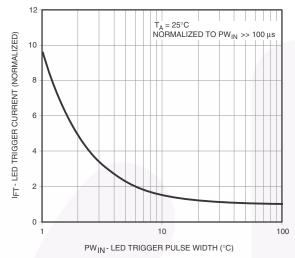


Fig. 7 LED Current Required to Trigger vs. LED Pulse Width

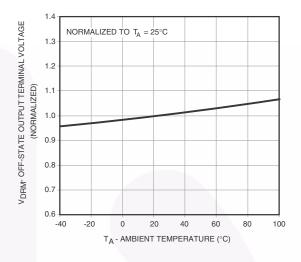
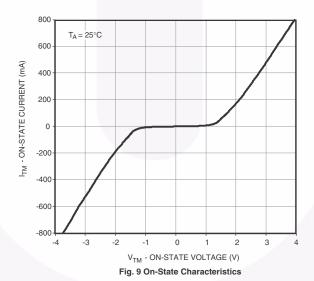
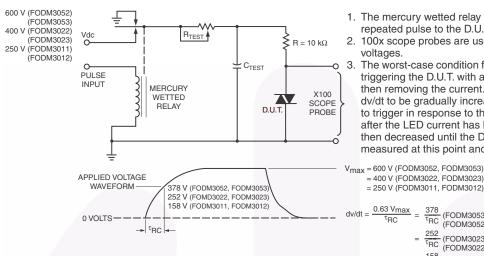


Fig. 8 Off-State Output Terminal Voltage vs. Ambient Temperature



# **Typical Application Information**



1. The mercury wetted relay provides a high speed repeated pulse to the D.U.T.

> (FODM3023) (FODM3022) (FODM3011)

(FODM3012)

- 100x scope probes are used, to allow high speeds and voltages.
- The worst-case condition for static dv/dt is established by triggering the D.U.T. with a normal LED input current, then removing the current. The variable R<sub>TEST</sub> allows the dv/dt to be gradually increased until the D.U.T. continues to trigger in response to the applied voltage pulse, even after the LED current has been removed. The dv/dt is then decreased until the D.U.T. stops triggering.  $\tau_{RC}$  is measured at this point and recorded.

= 400 V (FODM3022, FODM3023) = 250 V (FODM3011, FODM3012) 378 <sup>τ</sup>RC (FODM3053) (FODM3052) 0.63 V<sub>max</sub>

NOTE: This optoisolator should not be used to drive a load directly. It is intended to be a trigger device only.

Figure 10. Static dv/dt Test Circuit

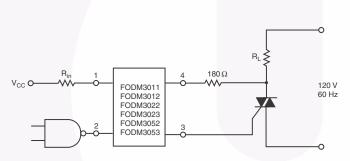


Figure 11. Resistive Load

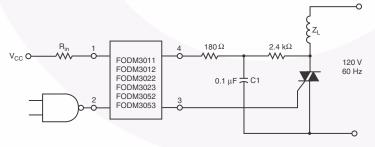
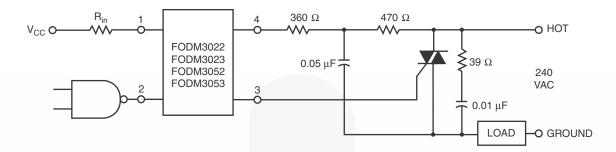


Figure 12. Inductive Load with Sensitive Gate Triac ( $I_{GT} \le 15 \text{ mA}$ )

# Typical Application Information (Continued)

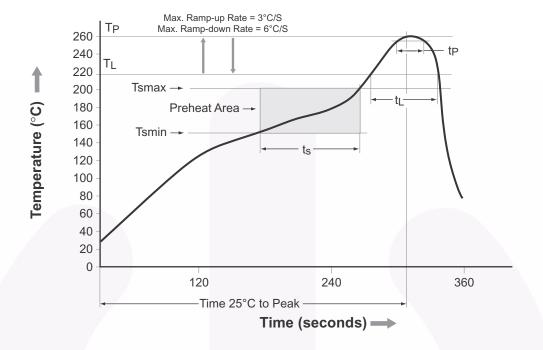


In this circuit the "hot" side of the line is switched and the load connected to the cold or ground side.

The 39  $\Omega$  resistor and 0.01 $\mu$ F capacitor are for snubbing of the triac, and the 470  $\Omega$  resistor and 0.05  $\mu$ F capacitor are for snubbing the coupler. These components may or may not be necessary depending upon the particular and load used.

**Figure 13. Typical Application Circuit** 

# **Reflow Profile**



| Profile Freature  | Pb-Free Assembly Profile |  |  |
|---|--------------------------|--|--|
| Temperature Min. (Tsmin)                                  | 150°C                    |  |  |
| Temperature Max. (Tsmax)                                  | 200°C                    |  |  |
| Time (t <sub>S</sub> ) from (Tsmin to Tsmax)              | 60-120 seconds           |  |  |
| Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )          | 3°C/second max.          |  |  |
| Liquidous Temperature (T <sub>L</sub> )                   | 217°C                    |  |  |
| Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> ) | 60-150 seconds           |  |  |
| Peak Body Package Temperature                             | 260°C +0°C / -5°C        |  |  |
| Time (t <sub>P</sub> ) within 5°C of 260°C                | 30 seconds               |  |  |
| Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )        | 6°C/second max.          |  |  |
| Time 25°C to Peak Temperature                             | 8 minutes max.           |  |  |

# **Ordering Information**

| Part Number | Package  | Packing Method             |
|-------------|--|----------------------------|
| FODM3011    | Full Pitch Mini-Flat 4-Pin                             | Tube (100 units)           |
| FODM3011R2  | Full Pitch Mini-Flat 4-Pin                             | Tape and Reel (2500 Units) |
| FODM3011V   | Full Pitch Mini-Flat 4-Pin, DIN EN/IEC60747-5-5 Option | Tube (100 Units)           |
| FODM3011R2V | Full Pitch Mini-Flat 4-Pin, DIN EN/IEC60747-5-5 Option | Tape and Reel (2500 Units) |

### Note:

The product orderable part number system listed in this table also applies to the FODM3012, FODM3022, FODM3023, FODM3052, and FODM3053 products.

# **Marking Information**

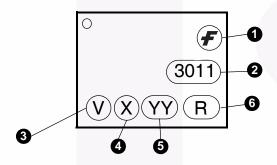
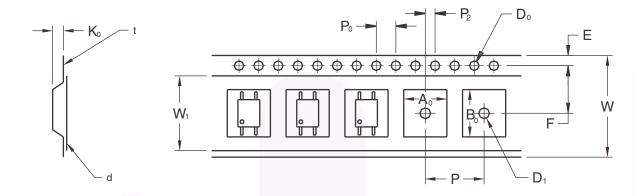


Figure 14. Top Mark

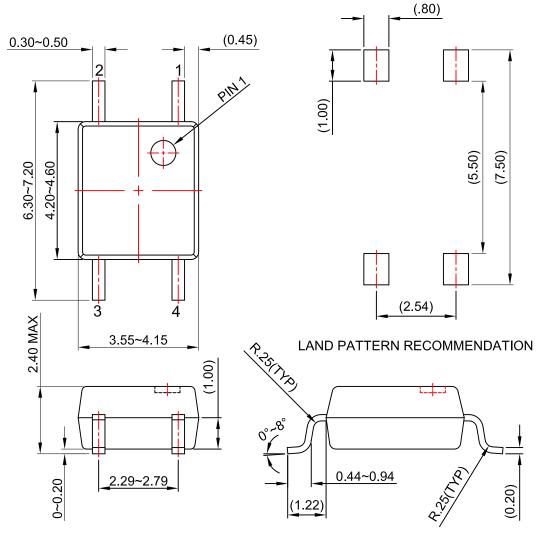
# **Table 1. Top Mark Definitions**

| 1 | Fairchild Logo  |
|---|---|
| 2 | Device Number   |
| 3 | DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option) |
| 4 | One-Digit Year Code, e.g., "6"  |
| 5 | Digit Work Week, Ranging from "01" to "53"                                      |
| 6 | Assembly Package Code   |

# **Tape Specifications**



|                                 |                | 2.54 Pitch   |
|---------------------------------|----------------|--------------|
| Description                     | Symbol         | Dimensions   |
| Tape Width                      | W              | 12.00±0.4    |
| Tape Thickness                  | t              | 0.35±0.02    |
| Sprocket Hole Pitch             | P <sub>0</sub> | 4.00±0.20    |
| Sprocket Hole Dia.              | D <sub>0</sub> | 1.55±0.20    |
| Sprocket Hole Location          | E              | 1.75±0.20    |
| Pocket Location                 | F              | 5.50±0.20    |
|                                 | P <sub>2</sub> | 2.00±0.20    |
| Pocket Pitch                    | Р              | 8.00±0.20    |
| Pocket Dimension                | A <sub>0</sub> | 4.75±0.20    |
|                                 | B <sub>0</sub> | 7.30±0.20    |
|                                 | K <sub>0</sub> | 2.30±0.20    |
| Pocket Hole Dia.                | D <sub>1</sub> | 1.55±0.20    |
| Cover Tape Width                | W <sub>1</sub> | 9.20         |
| Cover Tape Thickness            | d              | 0.065±0.02   |
| Max. Component Rotation or Tilt |                | 20° max      |
| Devices Per Reel                |                | 2500         |
| Reel Diameter                   |                | 330 mm (13") |



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